
	<p>JAN1N5417US</p>
	<p>Manufacturer Part Number: JAN1N5417US</p> <hr/> <p>Manufacturer/Brand: Microsemi</p> <hr/> <p>Part of Description: DIODE GEN PURP 200V 3A B-MELF</p> <hr/> <p>Datasheets:  JAN1N5417US.pdf</p> <hr/> <p>RoHs Status: Contains lead / RoHS non-compliant</p> <hr/> <p>Stock Condition: New original, Stock Available.</p> <hr/> <p>Ship From: Hong Kong</p> <hr/> <p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	









Specifications

Part Number	JAN1N5417US
Manufacturer	Microsemi
Description	DIODE GEN PURP 200V 3A B-MELF
Category	Discrete Semiconductor Products > Diodes - Rectifiers -
Part Status	Require For Quote & Check Stock
Voltage - Forward (Vf) (Max) @ If	1.5V @ 9A
Voltage - DC Reverse (Vr) (Max)	200V
Supplier Device Package	B, SQ-MELF
Speed	Fast Recovery = 200mA (Io)
Series	Military, MIL-PRF-19500/411
Reverse Recovery Time (trr)	150ns
Packaging	Bulk
Package / Case	SQ-MELF, B
Operating Temperature - Junction	-65°C ~ 175°C
Mounting Type	Surface Mount
Diode Type	Standard
Current - Reverse Leakage @ Vr	1µA @ 200V
Current - Average Rectified (Io)	3A
Capacitance @ Vr, F	-

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